



SCHOTTKY RECTIFIER

1 Amp

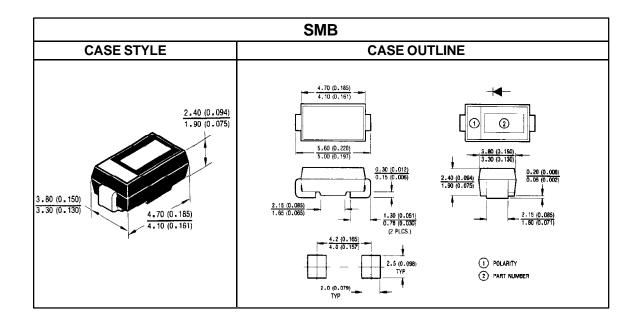
Major Ratings and Characteristics

Characteristics	10BQ040	Units
I _{F(AV)} Rectangular waveform	1.0	Α
V _{RRM}	40	V
I _{FSM} @ tp = 5µs sine	430	Α
V _F @ 1.0Apk, T _J = 125°C	0.49	V
TJ	-55 to 150	°C

Description / Features

The 10BQ040 surface-mount Schottky rectifier has been designed for applications requiring very low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging and reverse battery protection.

- Small footprint, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long-term reliability



Voltage Ratings

Part number		10BQ040	
V _R	Max. DC Reverse Voltage (V)	40	
V _{RWM}	Max. Working Peak Reverse Voltage (V)	40	

Absolute Maximum Ratings

	Parameters	10BQ	Units	Conditions		
I _{F(AV)}	Max. Average Forward Current	1.0	Α	50% duty cycle @ T _C = 112°C, rectangular waveform		
	See Fig. 5					
I _{FSM}	Max. Peak One Cycle Non - Repetitive	430	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition	
	Surge Current — see Fig. 7	45		10ms Sine 0r 6ms Rect. pulse	and with rated V _{RRM} applied.	
E _{AS}	Non - Repetitive Avalanche Energy	18	mJ	T _J = 25°C, I _{AS} = 0.2A, L = 13mH		
I _{AR}	Repetitive Avalanche Current	0.2	Α	Current decaying linearly to zero in 1µsec		
				Frequency limited by T _J max. V _A = 1.5 X V _R typical		

Electrical Specifications

Para	meters	10BQ	Units	nits Conditions	
V _{FM}	Max. Forward Voltage Drop	0.53	V	@ 1.0A	T _{.1} = 25°C
	See Fig. 1 ①	0.70	V	@ 2.0A	17-20 0
		0.49	V	@ 1.0A	T 10-00
		0.64	V	@ 2.0A	T _J = 125°C
I _{RM}	Max. Reverse Leakage Current ①	0.10	mA	$T_J = 25^{\circ}C$	$V_{\rm R}$ = rated $V_{\rm R}$
	See Fig. 2	4.0	mA	$T_J = 125$ °C	TK THE TK
Ст	Max. Junction Capacitance	80	pF	$V_R = 5V_{DC}$, (test signal range 100KHz to 1MHz) 25°C	
Ls	Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	5,300	V/µs		
	(Rated V _R)				

Thermal-Mechanical Specifications

	Parameters	10BQ	Units	Conditions
TJ	Max.Junction Temperature Range	-55 to 100	°C	
T _{STG}	Max. Storage Temperature Range	-55 to 100	°C	
R _{thJA}	Max. Thermal Resistance, Junction	140	°C/W	DC operation — See Fig. 4
	to Ambient			
R _{thJL}	Max. Thermal Resistance, Junction	36	°C/W	DC operation
	to Lead ②			
wt	Approximate Weight	0.10	g	
	Case Style	SMB		Similar to DO-214AA

 $^{\ \, \}mathbb O$ Pulse Width < 300 μs , Duty Cycle < 2%

② Mounted 1 inch square PCB, thermal probe connected to lead 2mm from package

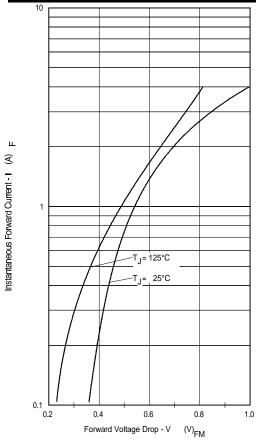
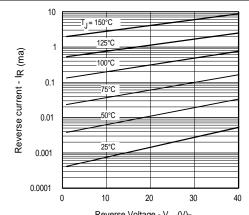


Fig. 1 Max. Forward Voltage Drop Characteristics



Reverse Voltage - V $\,$ (V)_{R} Fig. 2 Typical Values of Reverse Current Vs. Reverse Voltage

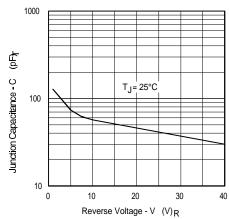
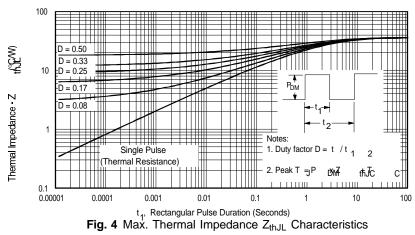


Fig. 3 Typical Junction CapacitanceVs. Reverse Voltage



10BQ040 **I∷R**

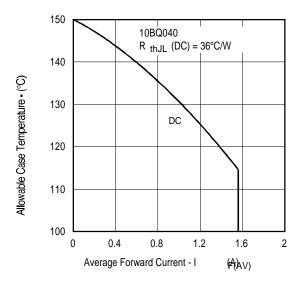


Fig. 5 Max. Allowable Case Temperature Vs.
Average Forward Current

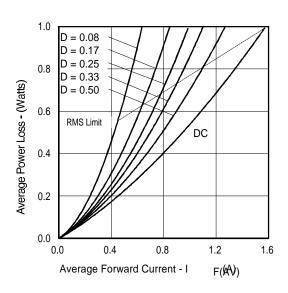


Fig. 6 Forward Power Loss Characteristics

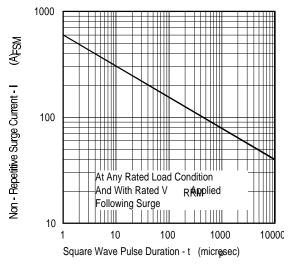


Fig.7 Max. Non-Repetitive Surge Current

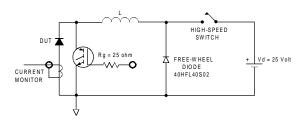


Fig. 8 Unclamped Inductive Test Circuit

Refer to the Appendix Section for the following:

Appendix D: Tape and Reel Information — See page 338.